PNP/NPN Epitaxial Planar Silicon Transistors

2SA1777/2SC4623



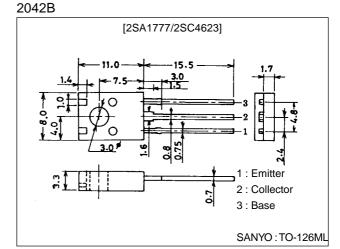
Very High-Definition CRT Display Video Output Applications

Features

- · High f_T : f_T =400MHz (typ).
- · High breakdown voltage : V_{CEO} \geq 250V(min).
- \cdot High current.
- \cdot Small reverse transfer capacitance and excellent high-frequnecy characteristic : $C_{re}=3.4pF$ (NPN), 4.2pF (PNP).
- \cdot Complementary pair with the 2SA1777/2SC4623.
- · Adoption of FBET process.

Package Dimensions

unit:mm



(): 2SA1777

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)250	V
Collector-to-Emitter Voltage	VCEO		(–)250	V
Emitter-to-Base Voltage	VEBO		(–)3	V
Collector Current	ΙC		(–)300	mA
Colletor Current (Pulse)	ICP		(–)600	mA
Collector Dissipation	PC		1.3	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)150V, I _E =0			(–)0.1	μA
Emitter Cutoff Current	IEBO	V _{EB} =(-)2V, I _C =0			(–)1.0	μA
DC Current Gain	h _{FE} 1	V _{CE} =(-)10V, I _C =(-)50mA	40*		200*	
	h _{FE} 2	V _{CE} =(-)10V, I _C =(-)250mA	20			
Gain-Bandwidth Product	fT	V _{CE} =(-)30V, I _C =(-)100mA		400		MHz
Output Capacitance	Cob	V _{CB} =(-)30V, f=1MHz		(5.0)		pF
				4.2		pF
Reverse Transfer Capacitance	C _{re}	V _{CB} =(-)30V, f=1MHz		(4.2)		pF
				3.4		pF

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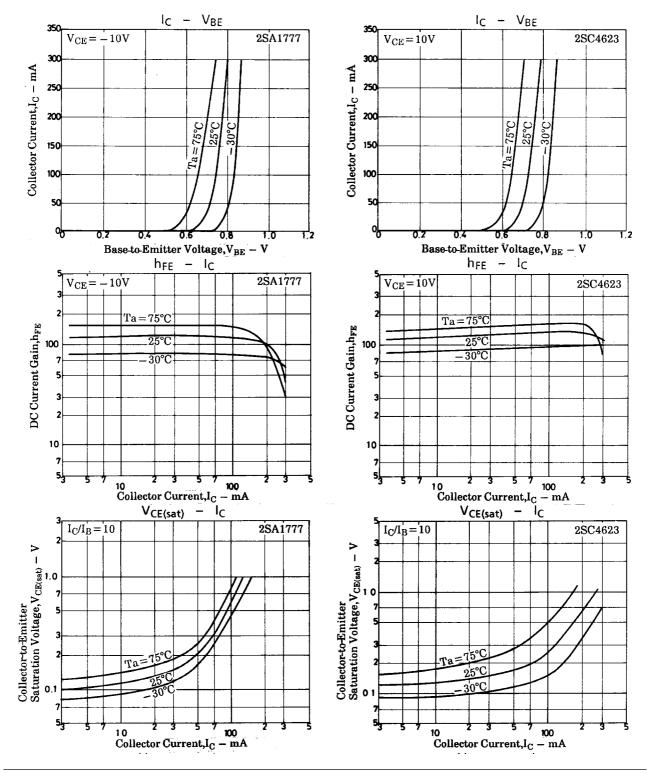
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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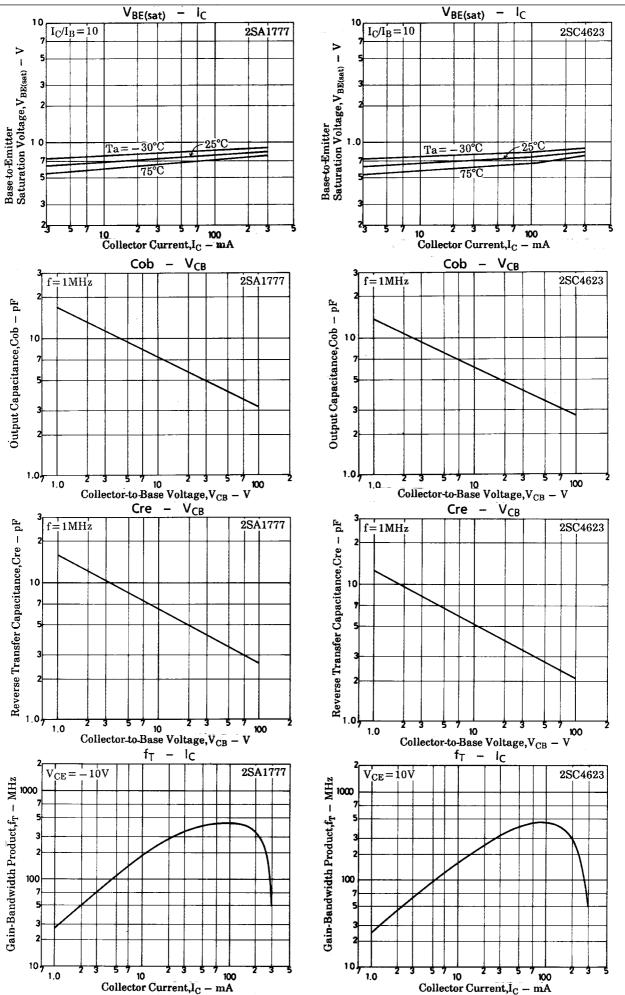
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(–)50mA, I _B =(–)5mA			()1.0	V
Base-to-Emitter Saturation Voltage	VBE(sat)	I _C =(-)50mA, I _B =(-)5mA			()1.0	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μA, I _E =0	(–)250			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(−)1mA, R _{BE} =∞	(–)250			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)10μΑ, I _C =0	(–)3			V

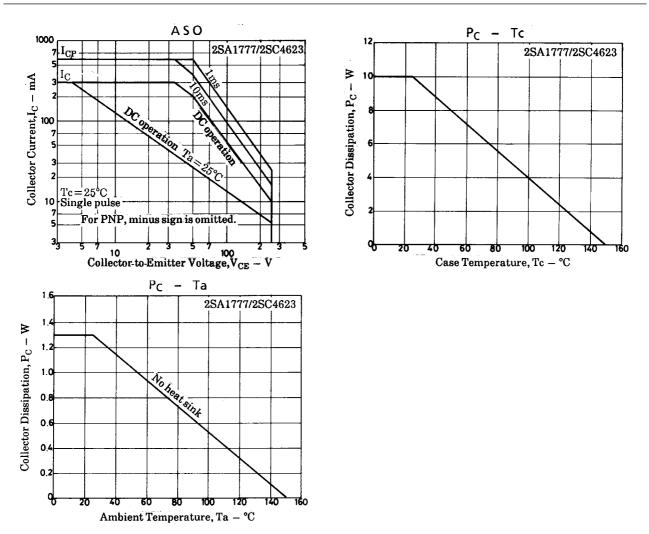
 \ast : The 2SA1777/2SC4623 are classified by 50mA h_{FE} as follows :

40 C 80 60 D 120 100 E 200



2SA1777/2SC4623





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